DSA7101

Silicon PNP epitaxial planar type

For low frequency amplification Complementary to DSC7101

Features

- \bullet Low collector-emitter saturation voltage $V_{\mbox{CE(sat)}}$
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)

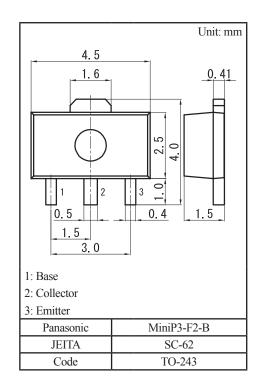
Marking Symbol: 4C

Packaging

DSA7101×0L Embossed type (Thermo-compression sealing): 1 000 pcs / reel (standard)

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	-80	V
Collector-emitter voltage (Base open)	V _{CEO}	-80	V
Emitter-base voltage (Collector open)	V _{EBO}	-5	V
Collector current	I _C	- 0.5	А
Peak collector current	I _{CP}	-1	А
Collector power dissipation *1	P _C	1	W
Junction temperature	Tj	150	°C
Operating ambient temperature	T _{opr}	-40 to +85	°C
Storage temperature	T _{stg}	-55 to +150	°C



Note) *1: Printed circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion Absolute maximum rating without heat sink for P_C is 0.5 W

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = -10 \ \mu {\rm A}, \ I_{\rm E} = 0$	-80			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = -100 \ \mu {\rm A}, I_{\rm B} = 0$	-80			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = -10 \ \mu A, I_{\rm C} = 0$	-5			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = -20 \text{ V}, I_E = 0$			- 0.1	μΑ
Forward current transfer ratio *1	h _{FE1} *2	$V_{CE} = -10 \text{ V}, I_C = -150 \text{ mA}$	90		220	
	h _{FE2}	$V_{CE} = -5 \text{ V}, I_C = -500 \text{ mA}$	50	100		
Collector-emitter saturation voltage *1	V _{CE(sat)}	$I_{\rm C} = -300 \text{ mA}, I_{\rm B} = -30 \text{ mA}$		- 0.2	- 0.4	V
Base-emitter saturation voltage *1	V _{BE(sat)}	$I_{\rm C} = -300 \text{ mA}, I_{\rm B} = -30 \text{ mA}$		- 0.9	-1.2	V
Transition frequency	f _T	$V_{CE} = -10 \text{ V}, I_C = -50 \text{ mA}$		120		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		10	30	pF

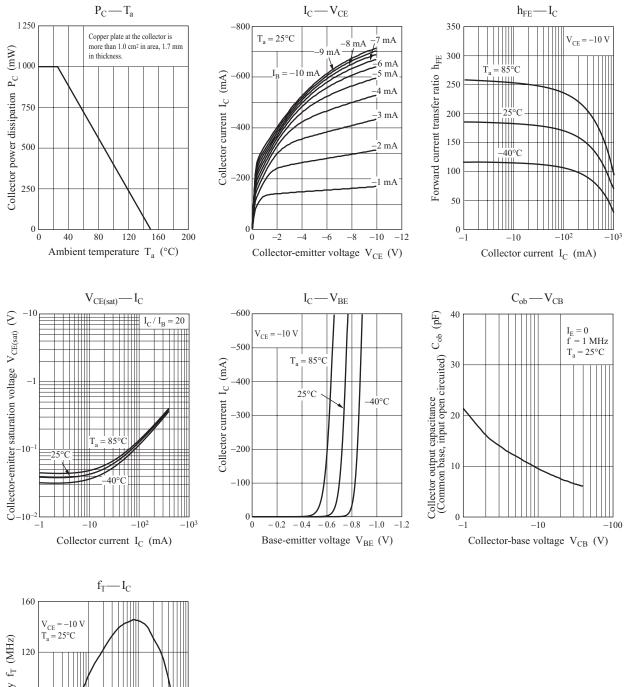
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement

*2: Rank classification			
Code	Q	R	0
Rank	Q	R	No-rank
h _{FE1}	90 to 155	130 to 220	90 to 220
Marking Symbol	4CQ	4CR	4C

Product of no-rank is not classified and have no marking symbol for rank.

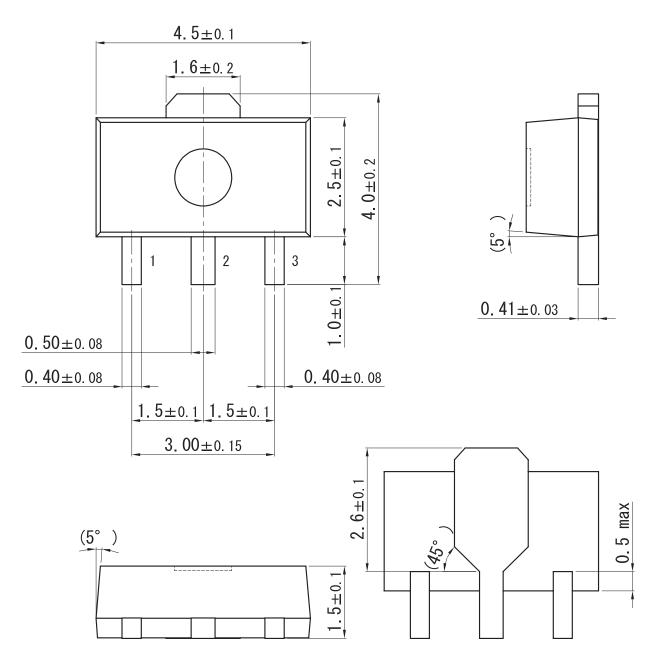
Panasonic



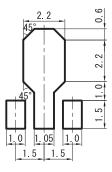
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MiniP3-F2-B

Unit: mm



Land Pattern (Reference) (Unit: mm)



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